

Date: 15.12.22

In continuous with the notice dated 02-12-22 regarding the position of JRF for the project entitled "Design, Optimization and Fabrication of Radiation Hardened Sub 0.15 micron gate length InAlN/GaN HEMT for Ku band application." under DST-SERB, the last date for the same has been extended till 20.12.22



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**"Design, Optimization and Fabrication of**  
**Radiation Hardened Sub 0.15 micron gate**  
**length InAlN / GaN HEMT for Ku band application."**